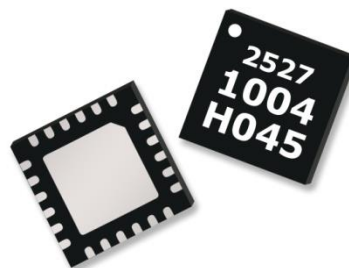


TGA2527-SM

Ku-Band Power Amplifier

Applications

- Point-to-Point Radio
- Ku-Band VSAT

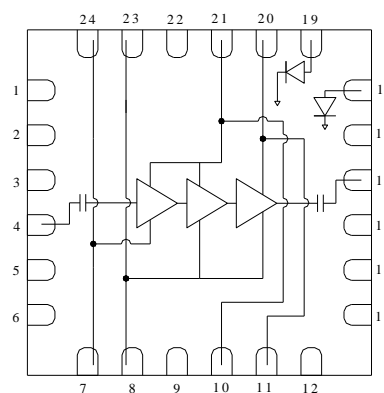


QFN 5x5mm 24L

Product Features

- Frequency Range: 12.5 – 15.5 GHz
- TOI: 41 dBm
- Power: 31.5 dBm Psat, 30 dBm P1dB
- Gain: 25 dB
- Return Loss: 10 dB
- NF: 7.5 dB
- Integrated Power Detector
- Bias: $V_d = 6\text{ V}$, $I_d = 650\text{ mA}$, $V_g = -0.55\text{ V}$ Typical
- Package Dimensions: 5.0 x 5.0 x 0.85 mm

Functional Block Diagram



General Description

The TriQuint TGA2527-SM is a Ku-Band Packaged Power Amplifier. The TGA2527-SM operates from 12.5 to 15.5 GHz and is designed using TriQuint's power pHEMT production process.

The TGA2527-SM typically provides 41dBm of TOI at 20dBm Pout/Tone, 30 dBm of output power at 1dB gain compression, and the small signal gain is 25 dB.

The TGA2527-SM is available in a low-cost, surface mount 24 lead 5x5 QFN package and is ideally suited for Point-to-Point Radio, and Ku-Band VSAT Ground Terminal.

Lead-free and RoHS compliant.

Evaluation Boards are available upon request.

Pin Configuration

Pin #	Symbol
1, 2, 3, 5, 6, 9, 12, 13, 14, 15, 17	N/C
4	RF IN
7, 8, 23, 24	V_g
16	RF OUT
10, 11, 20, 21	V_d
18	V_{ref}
19	V_{det}
22	GND

Ordering Information

Part No.	ECCN	Description
TGA2527-SM	EAR99	Ku-band Power Amplifier

Standard T/R size = 500 pieces on a 7" reel.

Specifications

Absolute Maximum Ratings

Parameter	Rating
Drain Voltage, Vd	+8 V
Gate Voltage, Vg	-3 to 0 V
Drain Current, Id	1.12 A
Gate Current, Ig	-5.5 to 88 mA
Power Dissipation, Pdiss	9 W
RF Input Power, CW, 50Ω, T = 25°C	24 dBm
Channel Temperature, Tch	200 °C
Mounting Temperature (30 Seconds)	260 °C
Storage Temperature	-40 to 150 °C

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied.

Recommended Operating Conditions

Parameter	Min	Typical	Max	Units
Vd		6		V
Id		650		mA
Id_drive (Under RF Drive)		850		mA
Vg		-0.55		V

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

Electrical Specifications

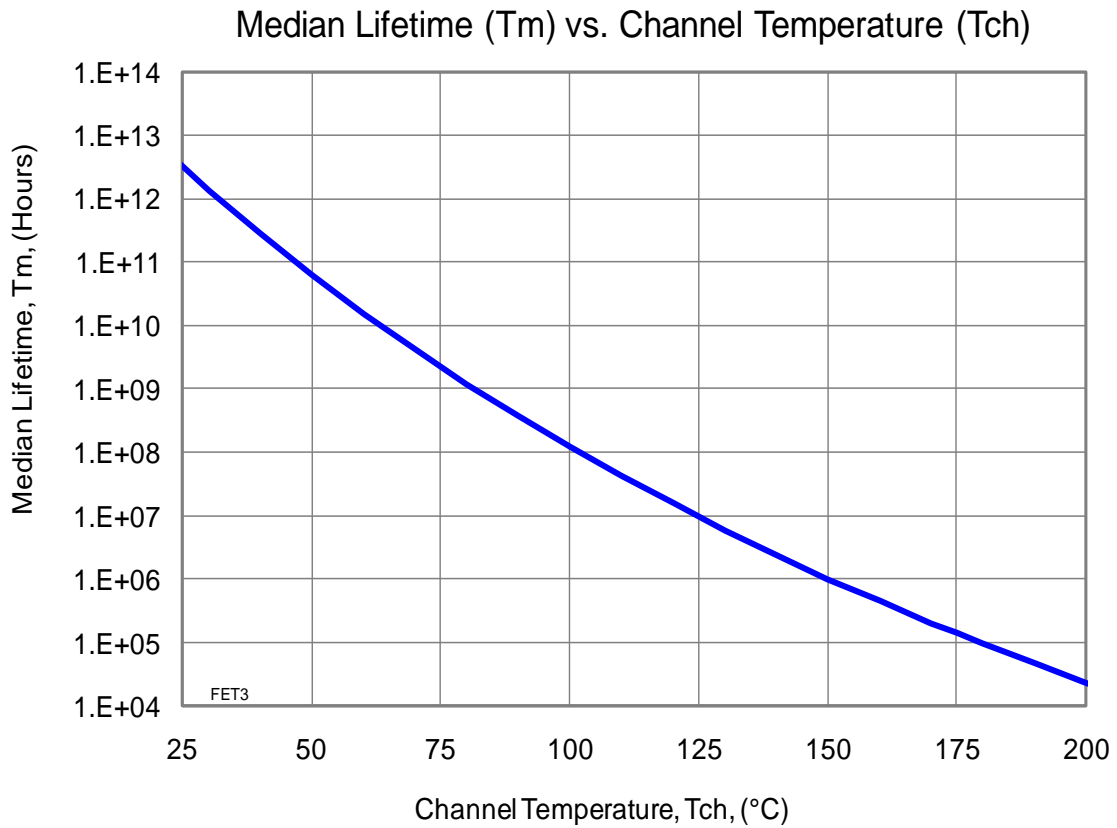
Test conditions unless otherwise noted: 25°C, Vd = 6 V, Id = 650 mA, Vg = -0.55 V Typical.

Parameter	Min	Typical	Max	Units
Operational Frequency Range	12.5		15.5	GHz
Gain		25		dB
Input Return Loss		-10		dB
Output Return Loss		-10		dB
Output Power @ Saturation		31.5		dBm
Output Power @ 1 dB Gain Compression		30		dBm
Output TOI @ Pout/Tone = 20 dBm		41		dBm
Noise Figure		7.5		dB
Gain Temperature Coefficient		-0.033		dB/°C
Power Temperature Coefficient		-0.005		dBm/°C

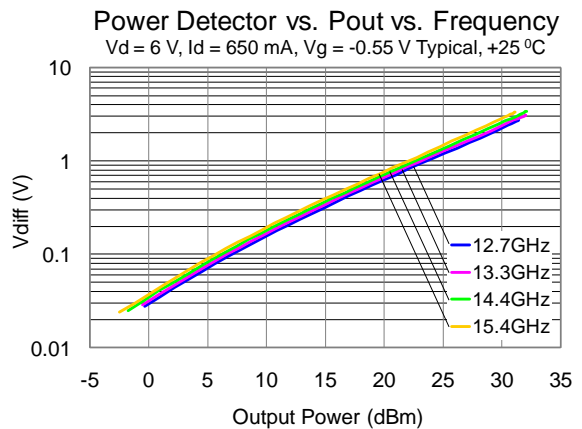
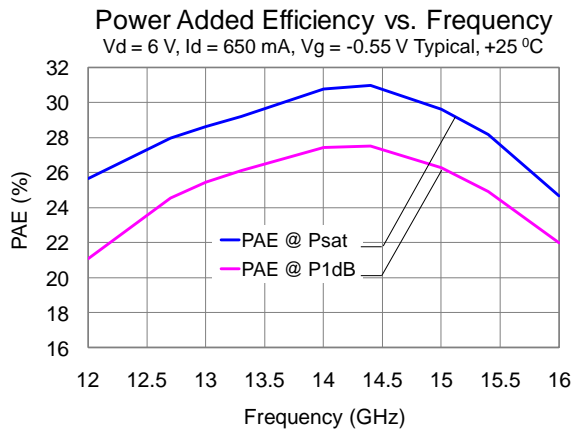
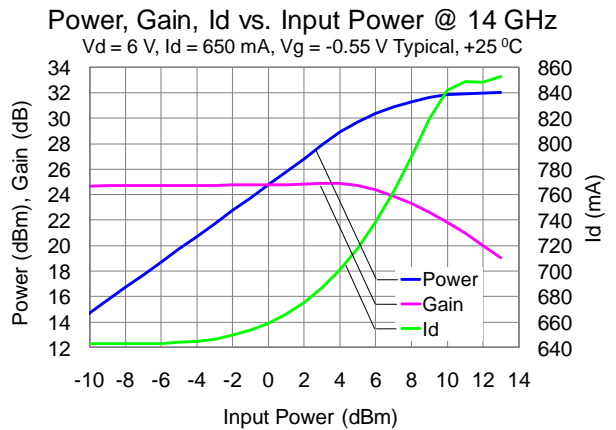
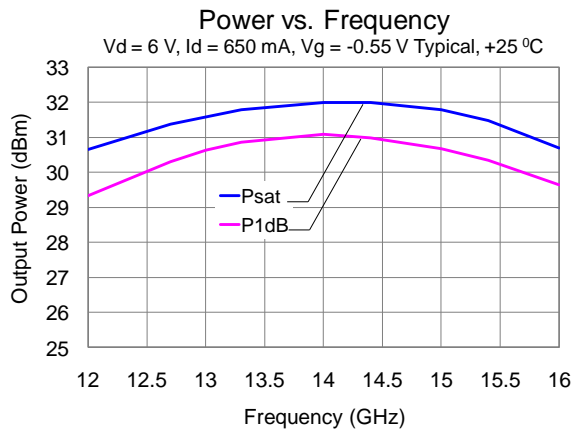
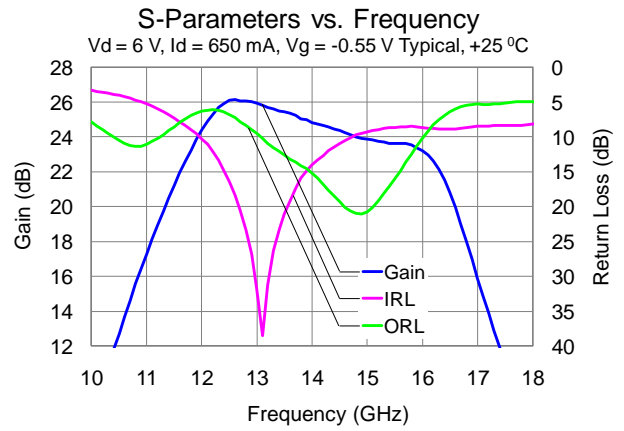
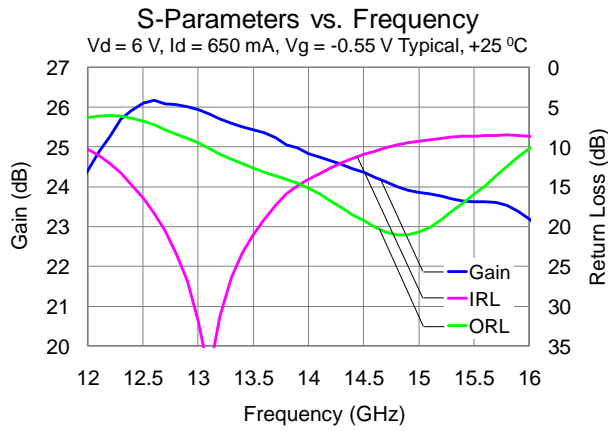
Specifications (cont.)

Thermal and Reliability Information

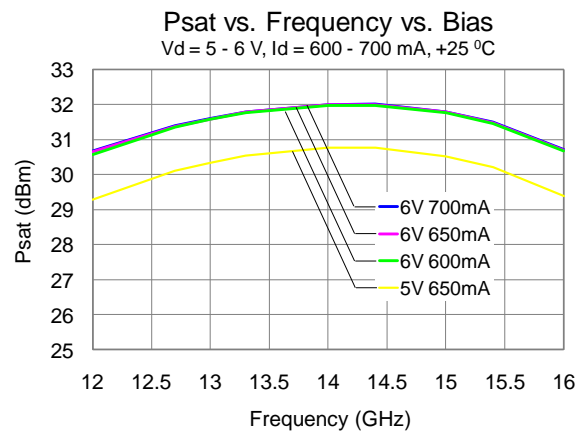
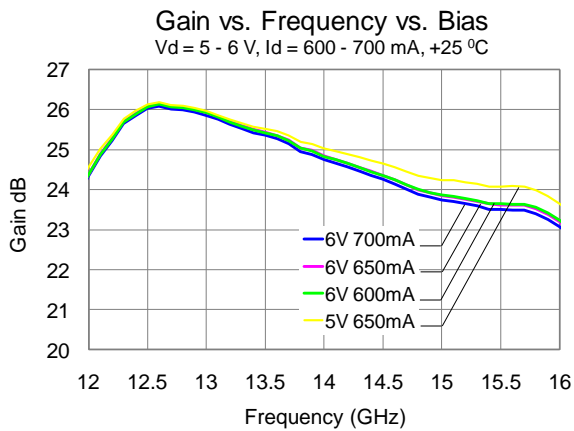
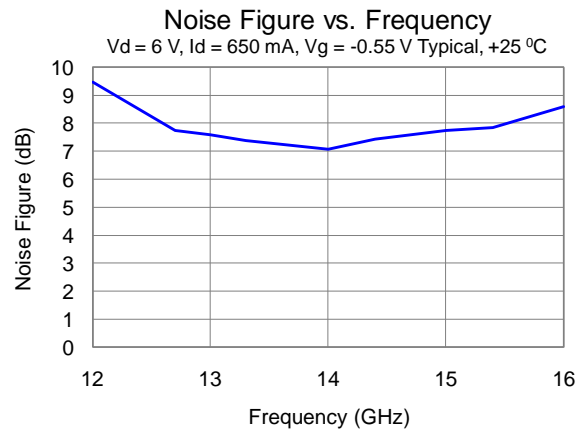
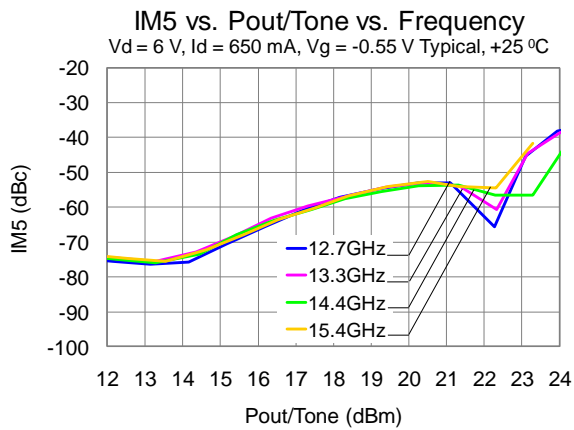
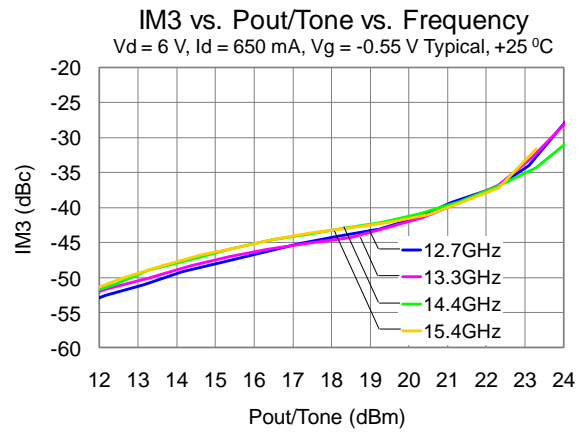
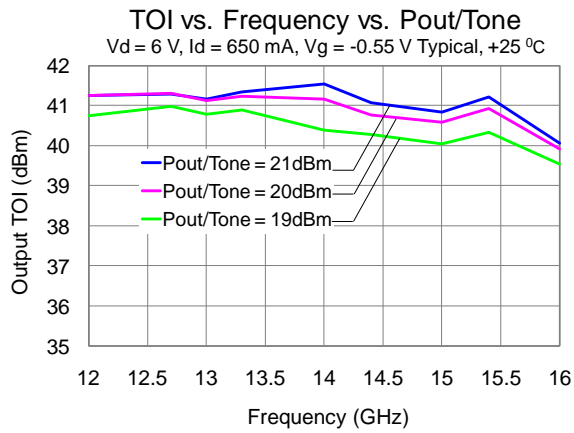
Parameter	Condition	Rating
Thermal Resistance, θ_{JC} , measured to back of package	Tbase = 85 °C	$\theta_{JC} = 11.5$ °C/W
Channel Temperature (Tch), and Median Lifetime (Tm)	Tbase = 85 °C, Vd = 6 V, Id = 650 mA, Pdis = 3.9 W	Tch = 130 °C Tm = 5.9 E+6 Hours
Channel Temperature (Tch), and Median Lifetime (Tm) Under RF Drive	Tbase = 85 °C, Vd = 6 V, Id = 850 mA, Pout = 32 dBm, Pdis = 3.5 W	Tch = 125 °C Tm = 9.5 E+6 Hours



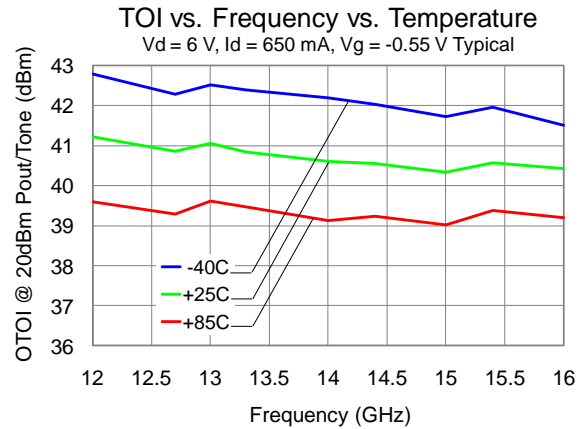
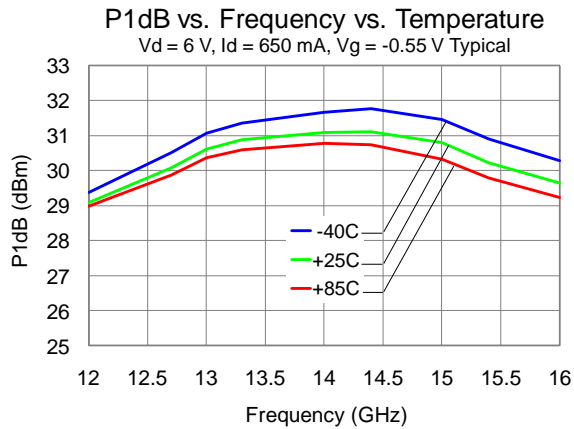
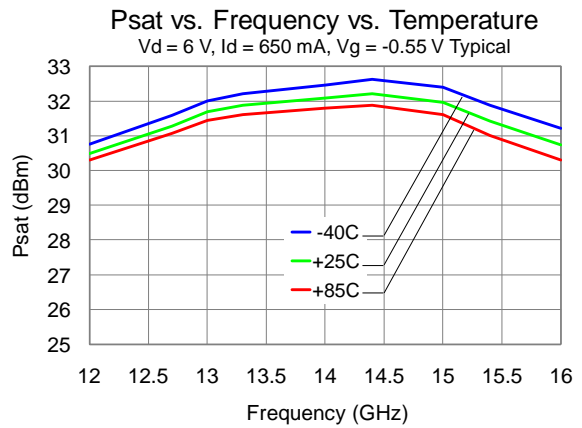
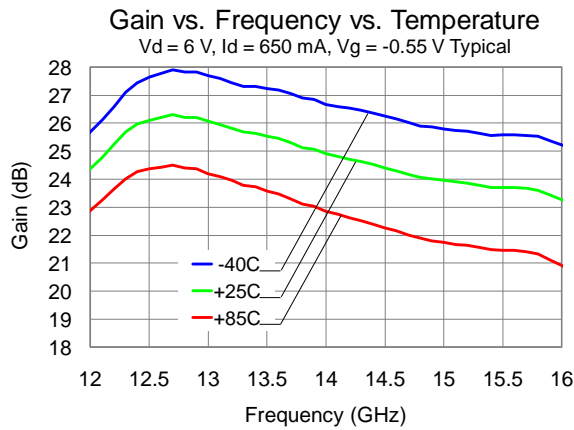
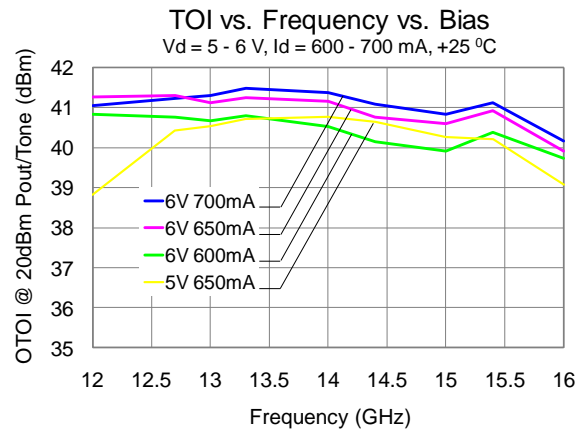
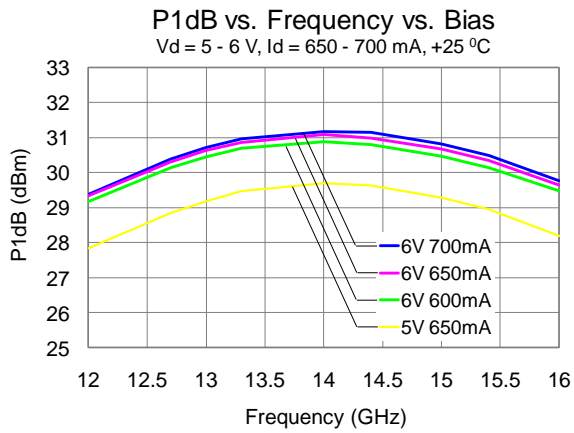
Typical Performance



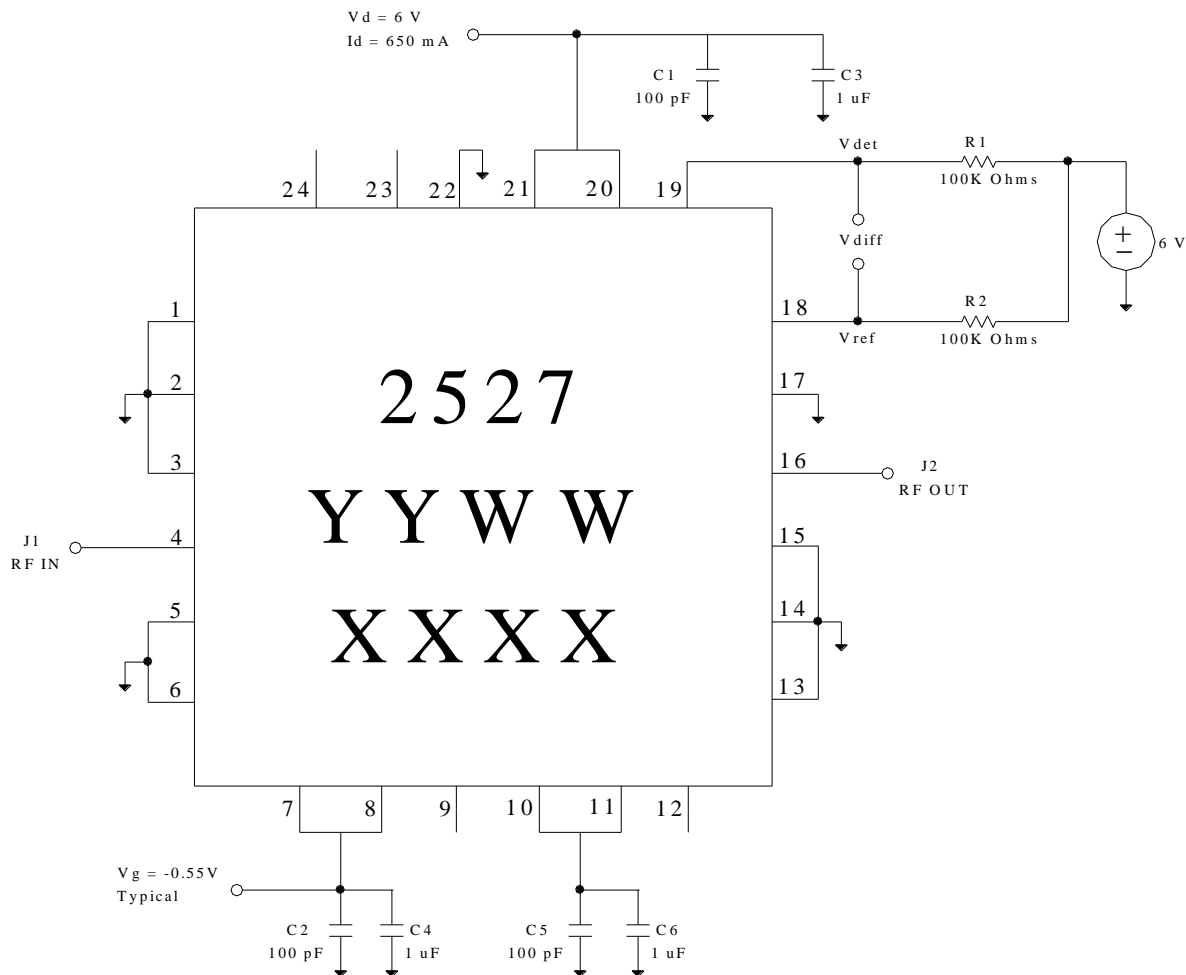
Typical Performance (cont.)



Typical Performance (cont.)



Application Circuit



Vg and Vd can be biased from either side, and the non-biased side Vg can be left open.
 Bypass caps are required on the Vd pins that are not DC biased (pins 10, 11, shown above).
 (Vg are either pins 7 and 8 or pins 23 and 24, Vd are either pins 10 and 11 or pins 20 and 21)

Bias-up Procedure

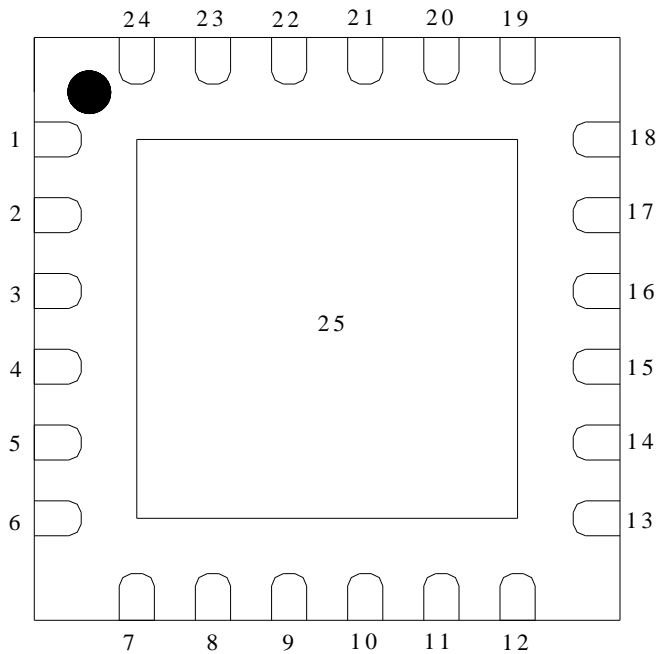
Vg set to -1.5 V
 Vd set to +6 V
 Adjust Vg more positive until quiescent Id is 650mA.
 This will be ~ Vg = -0.55 V
 Apply RF signal to RF Input

Bias-down Procedure

Turn off RF supply
 Reduce Vg to -1.5V. Ensure Id ~ 0 mA
 Turn Vd to 0 V
 Turn Vg to 0 V

The TGA2527-SM will be marked with the “2527” designator and a lot code marked below the part designator. The “YY” represents the last two digits of the year the part was manufactured, the “WW” is the work week, and the “XXXX” is an auto-generated number.

Pin Description



Pin	Symbol	Description
1, 2, 3, 5, 6, 13, 14, 15, 17	N/C	No internal connection; must be grounded on PCB
4	RF IN	Input, matched to 50 ohms
7, 8, 23, 24	V _g	Gate voltage. ESD protection included; Bias network is required; can be biased from either side (pins 7 and 8 or pins 23 and 24), and non-biased side can be left opened; see Application Circuit on page 7 as an example.
9, 12	N/C	No internal connection. Can be grounded on PCB or left open
10, 11, 20, 21	V _d	Drain voltage. Bias network is required; can be biased from either side (pins 10 and 11 or pins 20 and 21), and non-biased side requires bypass caps.; see Application Circuit on page 7 as an example.
16	RF OUT	Output, matched to 50 ohms
18	V _{ref}	Reference diode output voltage.
19	V _{det}	Detector diode output voltage. Varies with RF output power.
22	GND	Internal grounding; can be grounded on PCB or left open
25	GND	Backside Paddle. Multiple vias should be employed to minimize inductance and thermal resistance; see Mounting Configuration on page 11 for suggested footprint.

TGA2527-SM

Ku-Band Power Amplifier



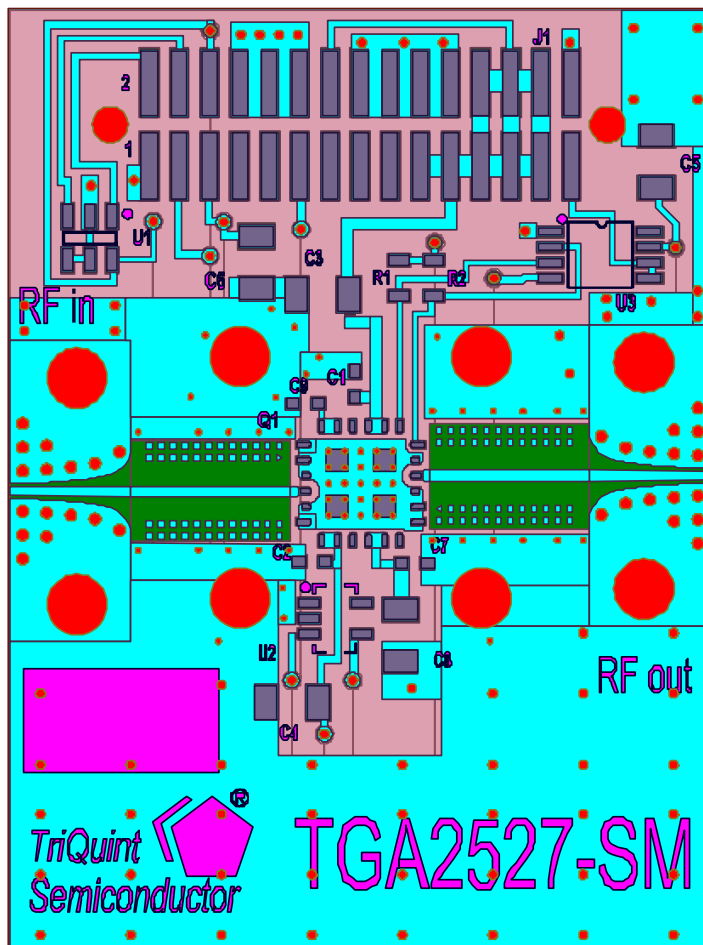
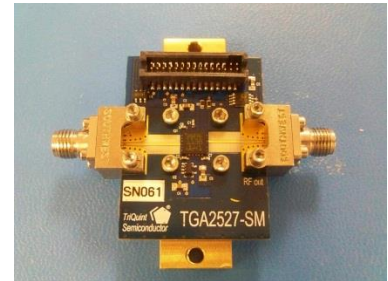
Applications Information

PC Board Layout

Top RF layer is 0.008” thick Rogers RO4003, $\epsilon_r = 3.38$. Metal layers are 1-oz copper. Microstrip 50 Ω line detail: width = 0.0175”.

The pad pattern shown has been developed and tested for optimized assembly at TriQuint Semiconductor. The PCB land pattern has been developed to accommodate lead and package tolerances. Since surface mount processes vary from company to company, careful process development is recommended.

For further technical information, refer to the [TGA2527-SM](#) Product Information page.



Bill of Material

Ref Des	Value	Description	Manufacturer	Part Number
C1, C2, C5	100 pF	Cap, 0402, 50 V, 5%, COG	various	
C3, C4, C6	1 uF	Cap, 0603, 25 V, 10%, X5R	various	
R1, R2	100K Ohms	Res, 0603, 1/16W, 5%, SMD	various	

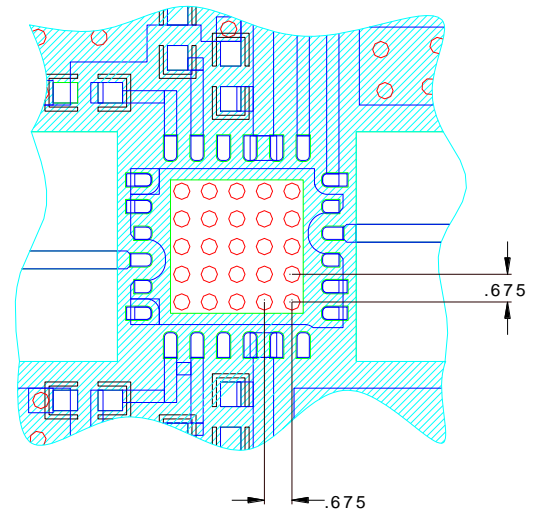
Mechanical Information (cont.)

Mounting Configuration

All dimensions are in millimeters (inches).

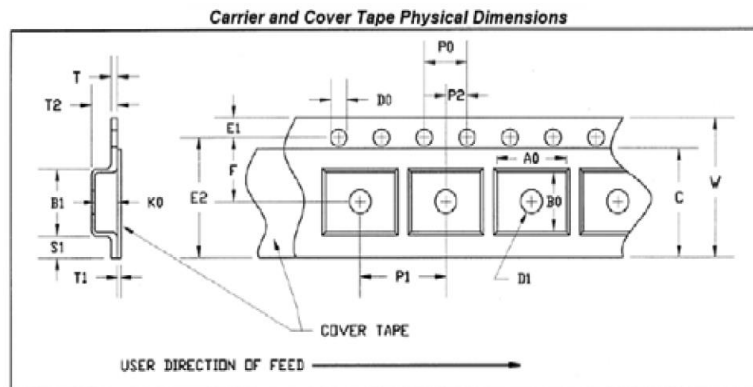
Notes:

1. A heatsink underneath the area of the PCB for the mounted device is recommended for proper thermal operation.
2. Ground / thermal vias are critical for the proper performance of this device. Vias have a final plated thru diameter of .40 mm (.016”).



Tape and Reel Information

Tape and reel specifications for this part are also available on the TriQuint website in the “Application Notes” section. Standard T/R size = 500 pieces on a 7 x 0.5” reel.



CARRIER AND COVER TAPE DIMENSIONS

Part	Feature	Symbol	Size (in)	Size (mm)
Cavity	Length	A0	0.207	5.25
	Width	B0	0.207	5.25
	Depth	K0	0.043	1.10
	Pitch	P1	0.315	8.00
Distance Between Centerline	Cavity to Perforation Length Direction	P2	0.079	2.00
	Cavity to Perforation Width Direction	F	0.217	5.50
Cover Tape	Width	C	0.374	9.5
Carrier Tape	Width	W	0.472	12.0

Product Compliance Information

ESD Information



Caution! ESD-Sensitive Device

ESD Rating: TBD
 Value: Passes \geq TBD min
 Test: Human Body Model (HBM)
 Standard: JEDEC Standard JESD22-A114

MSL Rating

Level MSL1 at +260 °C convection reflow
 The part is rated Moisture Sensitivity Level MSL1 at 260°C per JEDEC standard IPC/JEDEC J-STD-020.

ECCN

US Department of Commerce: EAR99

Solderability

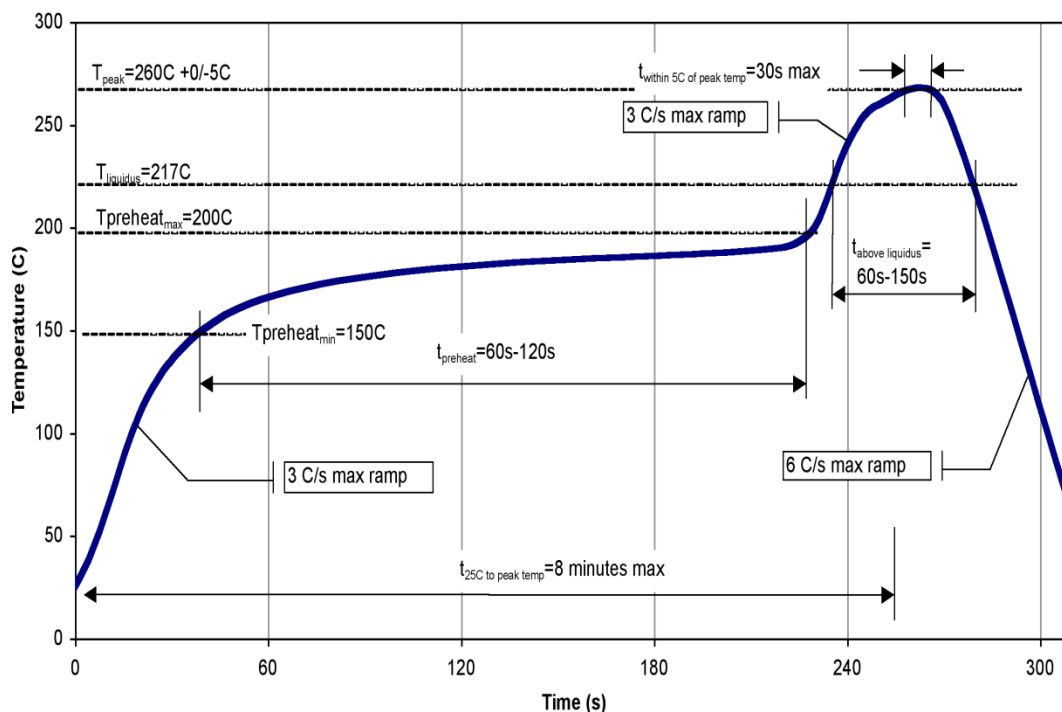
Compatible with the latest version of J-STD-020, Lead free solder, 260°C

This part is compliant with EU 2002/95/EC RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment).

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free
- PFOS Free
- SVHC Free

Recommended Soldering Temperature Profile



TGA2527-SM

Ku-Band Power Amplifier



Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations, and information about TriQuint:

Web: www.triquint.com
Email: info-sales@tqs.com

Tel: +1.972.994.8465
Fax: +1.972.994.8504

For technical questions and application information:

Email: info-networks@tqs.com

Important Notice

The information contained herein is believed to be reliable. TriQuint makes no warranties regarding the information contained herein. TriQuint assumes no responsibility or liability whatsoever for any of the information contained herein. TriQuint assumes no responsibility or liability whatsoever for the use of the information contained herein. The information contained herein is provided "AS IS, WHERE IS" and with all faults, and the entire risk associated with such information is entirely with the user. All information contained herein is subject to change without notice. Customers should obtain and verify the latest relevant information before placing orders for TriQuint products. The information contained herein or any use of such information does not grant, explicitly or implicitly, to any party any patent rights, licenses, or any other intellectual property rights, whether with regard to such information itself or anything described by such information.

TriQuint products are not warranted or authorized for use as critical components in medical, life-saving, or life-sustaining applications, or other applications where a failure would reasonably be expected to cause severe personal injury or death.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9